

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicants: Deane, Peter; Tsay, Chen H.; Wang, Albert
Assignee: National Semiconductor Corporation
Title: A Dual-Direction Over-Voltage And Over-Current IC Protection Device
And Its Cell Structure
Serial No.: Not known Filing Date: Not known
Examiner: Not known Group Art Unit: Not known
Docket No.: NS-3868-1C US

San Jose, California
October 23, 2001

BOX PATENT APPLICATION
COMMISSIONER FOR PATENTS
Washington, D. C. 20231

PRELIMINARY AMENDMENT

Dear Sir:

The present application is a continuation application of U.S. patent application ("Parent Application"), serial no. 09/100,384, filed on June 19, 1998. Please amend the above-referenced patent application as follows:

In the Specification

On page 1, insert at line 7, before the "BACKGROUND OF THE INVENTION" section:

CROSS-REFERENCE TO RELATED PATENT APPLICATIONS

This application is a continuation application of U.S. patent application, serial no. 09/100,384, entitled "A Dual-Direction Over-Voltage And Over-current IC Protection Device and Its Cell Structure," by Wang et al., assigned to Advanced Micro Devices, Inc., which is also the Assignee of the present application.

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